## NSN 5961-01-115-2660

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View Online at https://aerobasegroup.com/nsn/5961-01-115-2660 **Inclosure Material:** Metal **Overall Length:** 0.450 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-204 **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 550.0 breakdown voltage, collector-to-base, emitter open and 8.0 breakdown voltage, collector-to-emitter, base open and 400.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 15.00 amperes source cutoff current and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 175.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 1 case and 2 tab, solder lug **Specification Data:** 80131-release6732 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

Fiig:

No

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